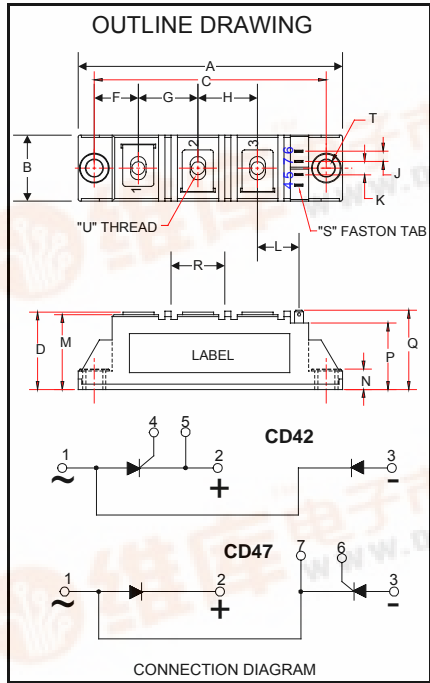


Powerex, Inc., Hillis Street, Youngwood, Pennsylvania 15697 (724) 925-7272

POW-R-BLOK™
Dual SCR/Diode Isolated Module
40 Amperes / Up to 1600 Volts



CD42__40A, CD47__40A
Dual SCR/Diode Isolated
POW-R-BLOK™ Module
40 Amperes / Up to 1600 Volts

Description:

Powerex SCR/Diode Modules are designed for use in applications requiring phase control and isolated packaging. The modules are isolated for easy mounting with other components on a common heatsink. POW-R-BLOK™ has been tested and recognized by the Underwriters Laboratories.

Features:

- Electrically Isolated Heatsinking
- DBC Alumina (Al₂O₃) Insulator
- Copper Baseplate
- Low Thermal Impedance for Improved Current Capability
- UL Recognized (E78240)

Benefits:

- No Additional Insulation Components Required
- Easy Installation
- No Clamping Components Required
- Reduce Engineering Time

Applications:

- Bridge Circuits
- AC & DC Motor Drives
- Battery Supplies
- Power Supplies
- Large IGBT Circuit Front Ends
- Lighting Control
- Heat & Temperature Control
- Welders

CD42, CD47 Outline Dimensions

Dimension	Inches	Millimeters
A	3.62	92
B	0.83	21
C	3.15	80
D	1.18	30
F	0.59	15
G	0.79	20
H	0.79	20
J	0.16	4
K	0.23	5.8
L	0.61	15.5
M	1.14	29
N	0.25	6.3
P	0.94	24
Q	1.18	30
R	0.71	18
S	0.11 x .03	2.8 x 0.8
T	0.25	6.3
U	M5	M5

Note: Dimensions are for reference only.

Ordering Information:

Select the complete nine digit module part number from the table below.
Example: CD421640A is a 1600Volt, 40 Ampere Dual SCR/Diode Isolated POW-R-BLOK™ Module

Type	Voltage Volts (x100)	Current Amperes (x 1)
CD42	08	40
CD47	12	16



**CD42__40A****CD47__40A**

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POW-R-BLOK™
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Characteristics	Conditions	Symbol	Units
Repetitive Peak Forward and Reverse Blocking Voltage		V_{DRM} & V_{RRM}	up to 1600 V
Non-Repetitive Peak Reverse Blocking Voltage ($t < 5$ msec)		V_{RSM}	$V_{RRM} + 100$ V
RMS Forward Current	180° Conduction, $T_C=91^\circ\text{C}$	$I_{T(RMS)}$	63 A
	180° Conduction, $T_C=91^\circ\text{C}$ (AC Switch)	$I_{T(RMS)}$	93 A
Average Forward Current	180° Conduction, $T_C=91^\circ\text{C}$	$I_{T(AV)}$	40 A
Peak One Cycle Surge Current, Non-Repetitive	60 Hz, 100% V_{RRM} reapplied, $T_J=125^\circ\text{C}$	I_{TSM}	750 A
	60 Hz, No V_{RRM} reapplied, $T_J=125^\circ\text{C}$	I_{TSM}	890 A
	60 Hz, No V_{RRM} reapplied, $T_J=25^\circ\text{C}$	I_{TSM}	985 A
	50 Hz, 100% V_{RRM} reapplied, $T_J=125^\circ\text{C}$	I_{TSM}	715 A
	50 Hz, No V_{RRM} reapplied, $T_J=125^\circ\text{C}$	I_{TSM}	850 A
	50 Hz, No V_{RRM} reapplied, $T_J=25^\circ\text{C}$	I_{TSM}	940 A
Peak Three Cycle Surge Current, Non-Repetitive	60 Hz, 100% V_{RRM} reapplied, $T_J=125^\circ\text{C}$	I_{TSM}	570 A
	50 Hz, 100% V_{RRM} reapplied, $T_J=125^\circ\text{C}$	I_{TSM}	545 A
Peak Ten Cycle Surge Current, Non-Repetitive	60 Hz, 100% V_{RRM} reapplied, $T_J=125^\circ\text{C}$	I_{TSM}	460 A
	50 Hz, 100% V_{RRM} reapplied, $T_J=125^\circ\text{C}$	I_{TSM}	445 A
I^2t for Fusing for One Cycle, 8.3 milliseconds	8.3 ms, 100% V_{RRM} reapplied, $T_J=125^\circ\text{C}$	I^2t	2,330 A^2sec
	8.3 ms, No V_{RRM} reapplied, $T_J=125^\circ\text{C}$	I^2t	3,300 A^2sec
	8.3 ms, No V_{RRM} reapplied, $T_J=25^\circ\text{C}$	I^2t	4,030 A^2sec
	10 ms, 100% V_{RRM} reapplied, $T_J=125^\circ\text{C}$	I^2t	2,560 A^2sec
	10 ms, No V_{RRM} reapplied, $T_J=125^\circ\text{C}$	I^2t	3,610 A^2sec
	10 ms, No V_{RRM} reapplied, $T_J=25^\circ\text{C}$	I^2t	4,420 A^2sec
Maximum Rate-of-Rise of On-State Current, (Non-Repetitive)	$T_J=25^\circ\text{C}$, $I_G=0.5$ A, $V_D=0.67 V_{DRM}$ (Rated), $I_{TM}=3000$ A, $T_r < 0.5\mu\text{s}$, $t_p > 6\mu\text{s}$	di/dt	150 A/ μs
Peak Gate Power Dissipation	$T_p < 5$ ms, $T_J = 125^\circ\text{C}$	P_{GM}	10 W
Average Gate Power Dissipation	$F = 50$ Hz, $T_J = 125^\circ\text{C}$	$P_{G(AV)}$	2.5 W
Peak Forward Gate Current	$T_p < 5$ ms, $T_J = 125^\circ\text{C}$	I_{GFM}	2.5 A
Peak Reverse Gate Voltage	$T_p < 5$ ms, $T_J = 125^\circ\text{C}$	V_{GRM}	10 V
Operating Temperature		T_J	-40 to +125 °C
Storage Temperature		T_{stg}	-40 to +125 °C
Max. Mounting Torque, M5 Mounting Screw on Terminals			25 in.-Lb.
			3 Nm
Max. Mounting Torque, Module to Heatsink			44 in.-Lb.
			5 Nm
Module Weight, Typical			110 g
			3.88 oz.
V Isolation @ 25C	50 – 60 Hz, 1 minute	V_{rms}	2500 V
Circuit to base, all terminals shorted together	50 – 60 Hz, 1 second	V_{rms}	3500 V



CD42__40A

CD47__40A

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Electrical Characteristics, T_J=25°C unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Max.	Units
Repetitive Peak Forward Leakage Current	I _{DRM}	Up to 1600V, T _J =125°C		15	mA
Repetitive Peak Reverse Leakage Current	I _{RRM}	Up to 1600V, T _J =125°C		15	mA
Peak On-State Voltage	V _{TM} / V _{FM}	I _{TM} / I _{FM} = 140A		1.81	V
Threshold Voltage, Low-level	V _{(TO)1}	T _J = 125°C, I = 16.7% x πI _{T(AV)} to πI _{T(AV)}		0.88	V
Slope Resistance, Low-level	r _{T1}			5.90	mΩ
Threshold Voltage, High-level	V _{(TO)2}	T _J = 125°C, I = πI _{T(AV)} to I _{TSM}		0.91	V
Slope Resistance, High-level	r _{T2}			5.74	mΩ
V _{TM} Coefficients, Full Range		T _J = 125°C, I = 15% x I _{T(AV)} to I _{TSM} V _{TM} = A + B Ln I + C I + D Sqrt I	A = B = C = D =	0.872 -1.86 E-3 5.65 E-3 4.33 E-3	
Minimum dV/dt	dV/dt	Linear to 2/3 V _{DRM} T _J =125°C, Gate Open Circuit	500		V/μs
Turn-Off Time (Typical)	t _{off}	T _J = 25°C, I _T = 2 A V _r = 50V, -dI/dt = 10 A/μs Re-Applied dV/dt = 200 V/μs, Linear to 900 V	40 - 100	(Typical)	μs
Gate Trigger Current	I _{GT}	T _J = -40°C, V _D =6V, Resistive Load T _J = 25°C, V _D =6V, Resistive Load T _J =125°C, V _D =6V, Resistive Load		270 150 80	mA mA mA
Gate Trigger Voltage	V _{GT}	T _J = -40°C, V _D =6V, Resistive Load T _J = 25°C, V _D =6V, Resistive Load T _J =125°C, V _D =6V, Resistive Load		4.0 2.5 1.7	Volts Volts Volts
Non-Triggering Gate Voltage	V _{GDM}	T _J =125°C, V _D =V _{DRM}		0.25	Volts
Non-Triggering Gate Current	I _{GDM}	T _J =125°C, V _D =V _{DRM}		6	mA
Holding Current	I _H	V _D =6V, Resistive Load, Gate Open		200	mA
Latching Current	I _L	V _D =6V, Resistive Load		400	mA

Thermal Characteristics

Characteristics	Symbol		Max.	Units
Thermal Resistance, Junction to Case DC Operation	R _{ΘJ-C}	Per Module, both conducting Per Junction, both conducting	0.230 0.460	°C/W °C/W
Thermal Impedance Coefficients	Z _{ΘJ-C}	Z _{ΘJ-C} = K ₁ (1-exp(-t/τ ₁)) + K ₂ (1-exp(-t/τ ₂)) + K ₃ (1-exp(-t/τ ₃)) + K ₄ (1-exp(-t/τ ₄))	K ₁ = 1.77 E-2 K ₂ = -1.00 E-2 K ₃ = 1.46 E-1 K ₄ = 3.07 E-1	τ ₁ = 4.73 E-4 τ ₂ = 1.67 E-3 τ ₃ = 9.77 E-3 τ ₄ = 8.76 E-2
Thermal Resistance, Case to Sink Lubricated	R _{ΘC-S}	Per Module	0.1	°C/W

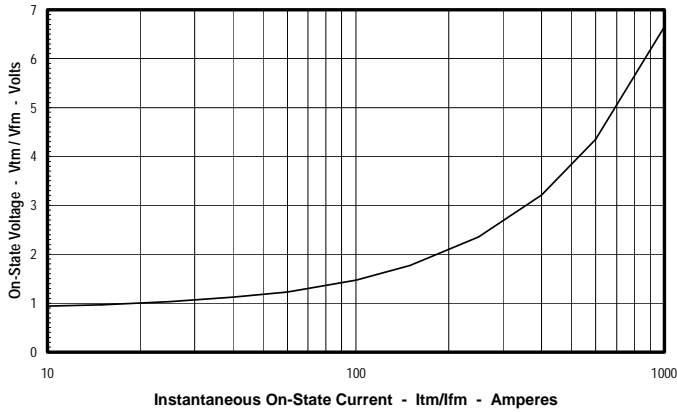


CD42_40A
CD47_40A

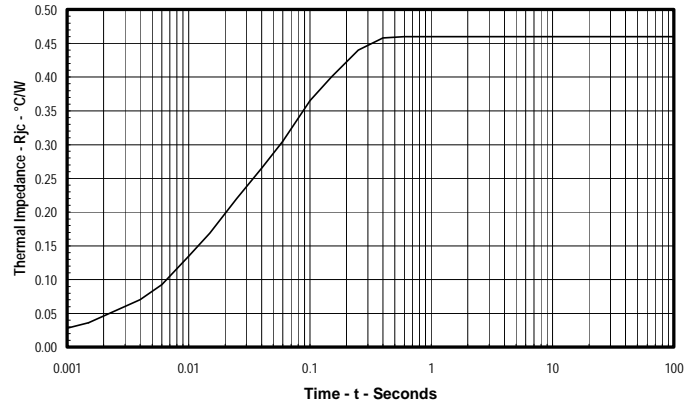
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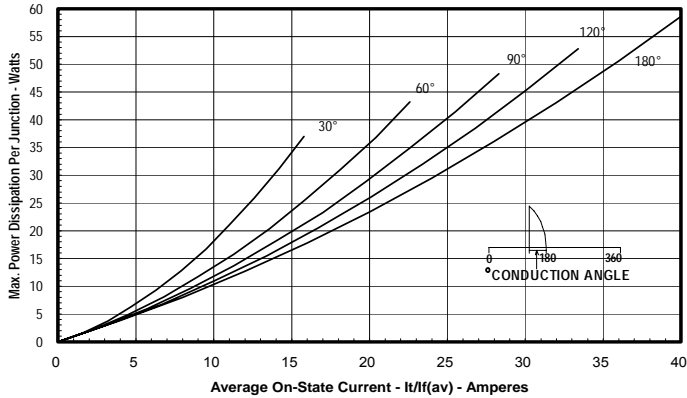
Maximum On-State Forward Voltage Drop
($T_j = 125^\circ\text{C}$)



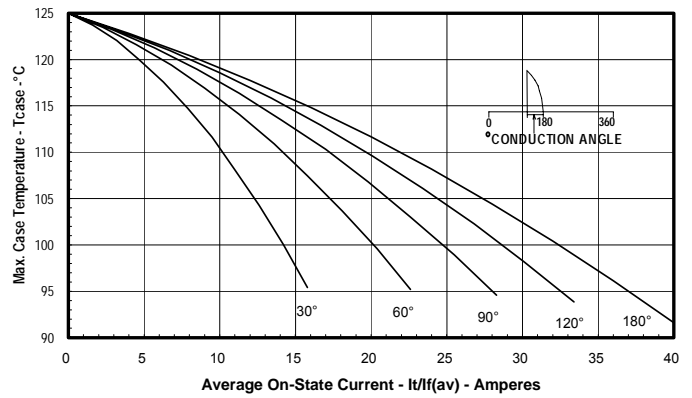
Maximum Transient Thermal Impedance
(Junction to Case)



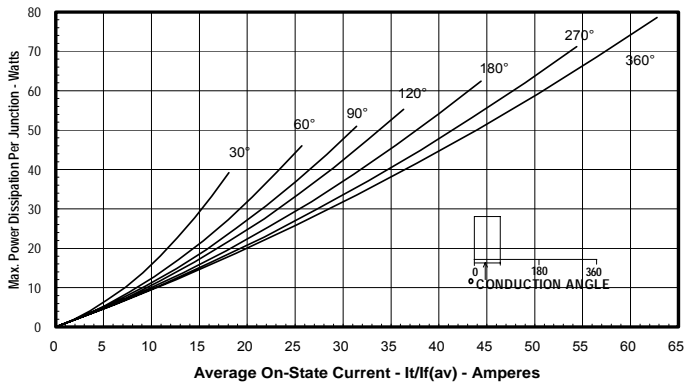
Maximum On-State Power Dissipation
(Sinusoidal Waveform)



Maximum Allowable Case Temperature
(Sinusoidal Waveform)



Maximum On-State Power Dissipation
(Rectangular Waveform)



Maximum Allowable Case Temperature
(Rectangular Waveform)

